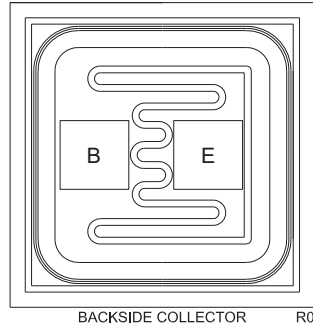


CP736V-2N3635

PNP - High Voltage Transistor Die

1.0 Amp, 140 Volt

The CP736V-2N3635 die is a PNP silicon transistor designed for high voltage amplifier applications.



MECHANICAL SPECIFICATIONS:

Die Size	17.3 x 17.3 MILS
Die Thickness	7.1 MILS
Base Bonding Pad Size	3.9 x 3.9 MILS
Emitter Bonding Pad Size	3.9 x 3.9 MILS
Top Side Metalization	Al-Si - 17,000Å
Back Side Metalization	Au - 9,000Å
Scribe Alley Width	1.8 MILS
Wafer Diameter	5 INCHES
Gross Die Per Wafer	57,735

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	140	V
Collector-Emitter Voltage	V_{CEO}	140	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I_C	1.0	A
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=100\text{V}$		100	nA
I_{EBO}	$V_{EB}=3.0\text{V}$		50	nA
BV_{CBO}	$I_C=100\mu\text{A}$	140		V
BV_{CEO}	$I_C=10\text{mA}$	140		V
BV_{EBO}	$I_E=10\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.3	V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$		0.5	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.8	V
$V_{BE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$	0.65	0.9	V
h_{FE}	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	80		
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	90		
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	100		
h_{FE}	$V_{CE}=10\text{V}, I_C=50\text{mA}$	100	300	
h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}$	50		
h_{fe}	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=1.0\text{kHz}$	80	320	
f_T	$V_{CE}=30\text{V}, I_C=30\text{mA}, f=100\text{MHz}$	200		MHz

R1 (23-May 2017)

CP736V-2N3635

PNP - High Voltage Transistor Die

1.0 Amp, 140 Volt

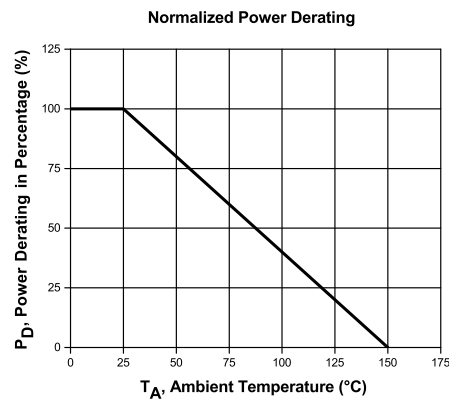
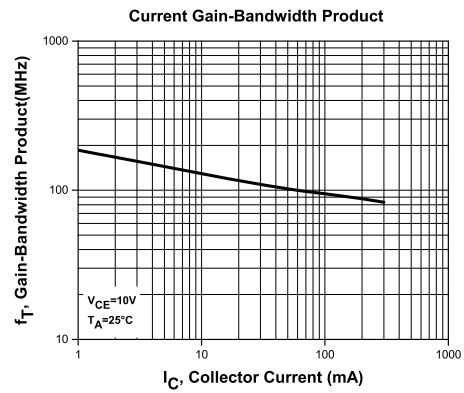
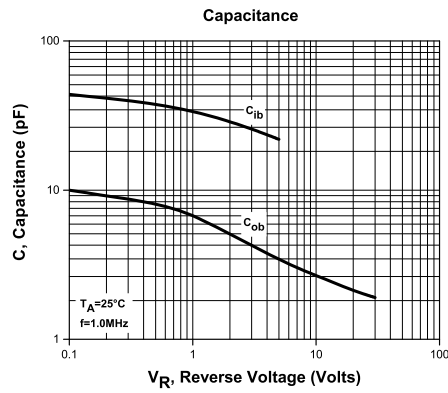
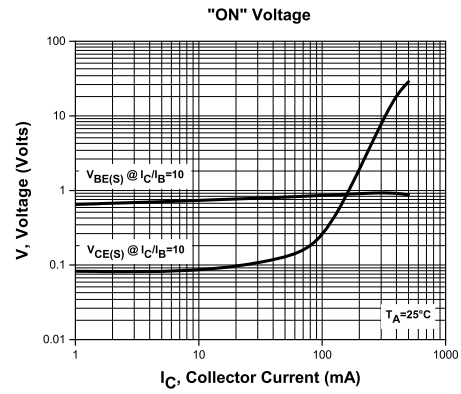
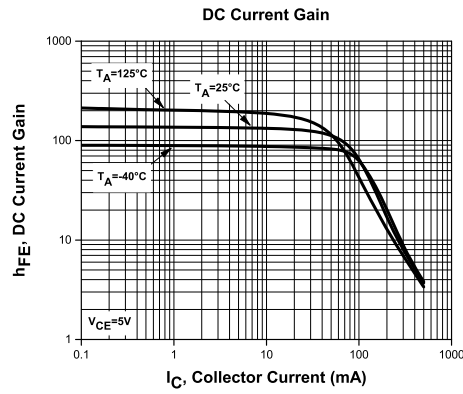


ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

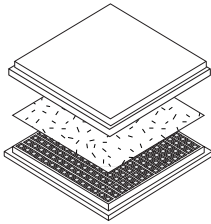
SYMBOL	TEST CONDITIONS	MAX	UNITS
C_{ob}	$V_{CB}=20\text{V}$, $I_E=0$, $f=1.0\text{MHz}$	10	pF
C_{ib}	$V_{EB}=1.0\text{V}$, $I_C=0$, $f=1.0\text{MHz}$	75	pF
NF	$V_{CE}=10\text{V}$, $I_C=0.5\text{mA}$, $R_S=1.0\text{k}\Omega$, $f=1.0\text{kHz}$	3.0	dB
t_{on}	$V_{CC}=100\text{V}$, $V_{BE}=4.0\text{V}$, $I_C=50\text{mA}$, $I_{B1}=I_{B2}=5.0\text{mA}$	400	ns
t_{off}		600	ns

CP736V-2N3635

Typical Electrical Characteristics



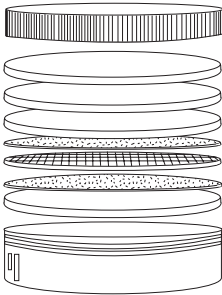
BARE DIE PACKING OPTIONS



BARE DIE IN TRAY (WAFFLE) PACK

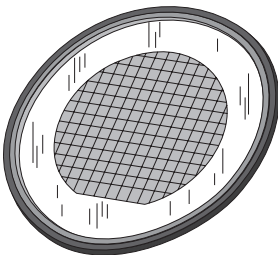
CT: Singulated die in tray (waffle) pack.
(example: CP211-PART NUMBER-CT)

CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes).
(example: CP211-PART NUMBER-CM)



UNSAWN WAFER

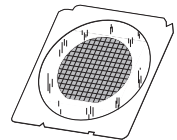
WN: Full wafer, unsawn, 100% tested with reject die inked.
(example: CP211-PART NUMBER-WN)



SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring, 100% tested with reject die inked.
(example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



Visit the Central website for a complete listing of specifications:
www.centrasemi.com/bdspecs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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